

LLSD103A THRU LLSD103C

Schottky Barrier Switching Diode

Features

- Lead Free Finish/Rohs Compliant (Note1) ("P" Suffix designates Compliant. See ordering information)
- Low Reverse Recovery Time
- Low Forward Voltage Drop and Low Reverse Capacitance
- Guard Ring Construction for Transient Protection

Mechanical Data

- Case: MiniMELF, Glass
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: Indicated by Cathode Band
- Weight: 0.05 grams (approx.)

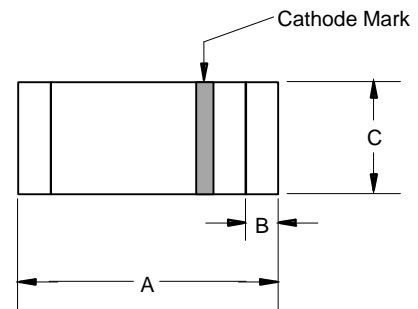
Maximum Ratings @ 25°C Unless Otherwise Specified

Characteristic	Symbol	LLSD103A	LLSD103B	LLSD103C
Peak Repetitive Reverse Voltage	V_{RRM}			
Working Peak Reverse Voltage	V_{RWM}	40V	30V	20V
DC Blocking Voltage	V_R			
RMS Reverse Voltage	$V_{R(RMS)}$	28V	21V	14V
Forward Continuous Current(Note2)	I_{FM}	350mA		
Maximum Single cycle surge 60Hz sine wave	I_{FSM}	15A		
Power Dissipation(Note 2)	P_d	400mW		
Thermal Resistance(Note 2)	R	250K/W		
Operation/Storage Temp. Range	T_j, T_{STG}	-55 to 150 °C		

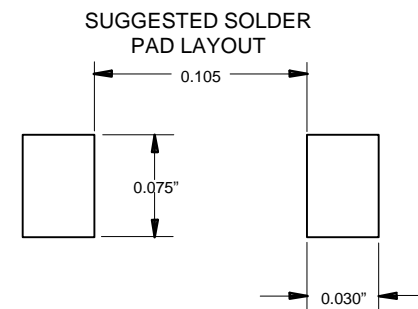
Electrical Characteristics @ 25°C Unless Otherwise Specified

Charateristic	Symbol	Min	Typ	Max	Test Cond.
Peak Reverse Current	I_{RM}	-----	-----	5.0uA	$V_R=30V$ $V_R=20V$ $V_R=10V$
Maximum Forward Voltage Drop	V_{FM}	-----	-----	0.37V 0.60V	$I_F=20mA$ $I_F=200mA$
Junction Capacitance	C_j	-----	50	pF	$V_R=0V, f=1.0MHz$
Reverse Recovery Time	t_{rr}	-----	10	ns	$I_F=I_R=50mA$ to 200mA, recover to 0.1 I_R

Note:1.Lead in Glass Exemption Applied, see EU Directive Annex 5.
2.Valid provided that electrodes are kept at ambient temperature



DIM	DIMENSION				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	.134	.142	3.40	3.60	
B	.008	.016	0.20	0.40	
C	.055	.059	1.40	1.50	



LLSD103A thru LLSD103C

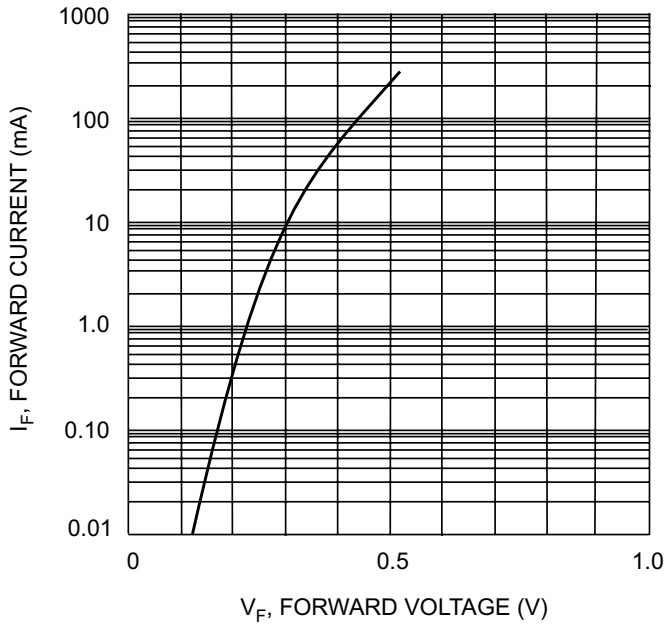


Fig. 1 Typical Forward Characteristics

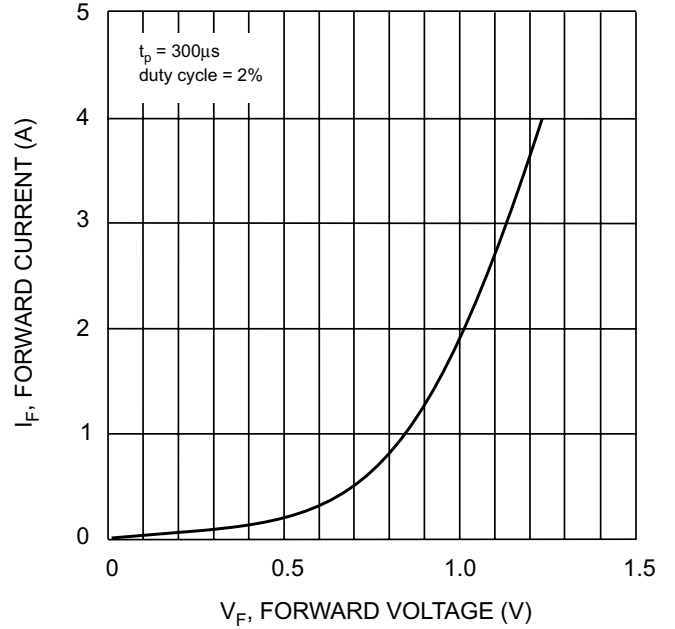


Fig. 2 Typical High Current Fwd Characteristics

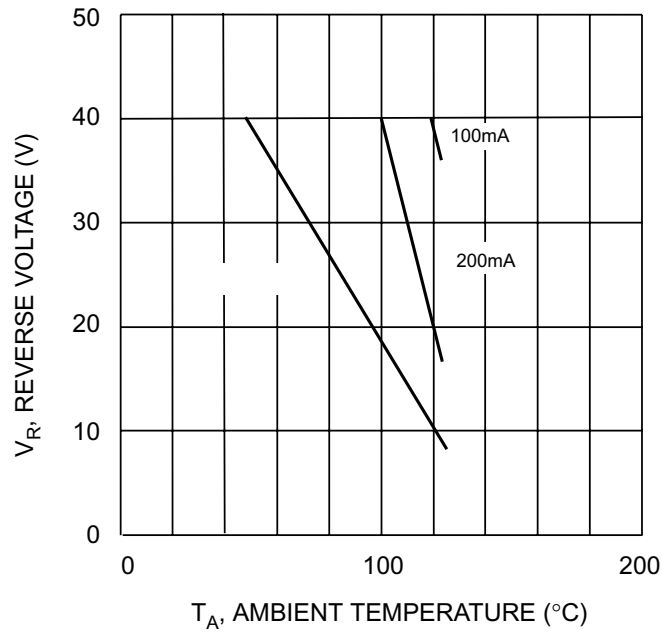


Fig. 3 Blocking Voltage Derating Curves

Ordering Information

Device	Packing
(Part Number)-TP	Tape&Reel;2.5Kpcs/Reel

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